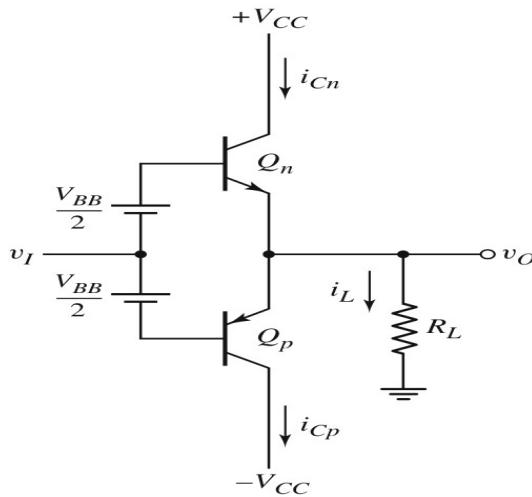


**Question:**



**Figure 1**

For the **class AB** output stage in **Figure 1**, given that  $V_{CC} = 12 \text{ V}$  and  $V_{BB} = 1.44 \text{ V}$ .  $R_L = 1 \text{ k}\Omega$ . The reverse-bias saturation current for the transistors,  $I_S = 2.2 \times 10^{-15} \text{ A}$ . Assume  $\beta \gg 1$ .

For the output voltage  $v_O = -9.5 \text{ V}$ :

- (i) Determine  $i_L$ ,  $i_{Cn}$ , and  $i_{Cp}$ . [8 marks]
- (ii) Find the power dissipated in transistor  $Q_n$ . [2 marks]

**Answer:** (You may continue your answer in the next page)

$$v_O = -9.5 \text{ V} = i_L R_L \\ i_L = v_O / R_L = (-9.5 \text{ V}) / (1 \text{ k}\Omega) = -9.5 \text{ mA} \quad [1]$$

Therefore,  $Q_p$  is conducting and  $Q_n$  is OFF.

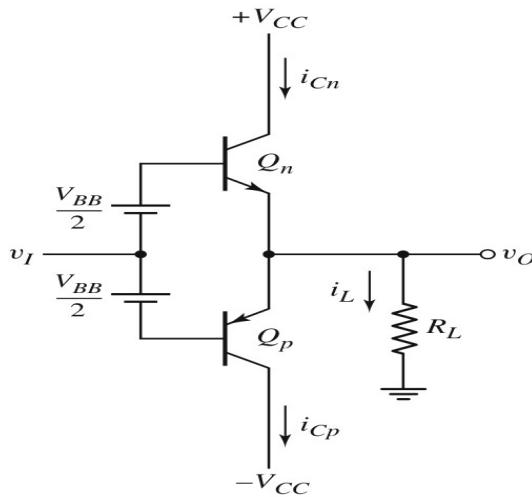
$$i_L \approx i_{Cp} = I_S \exp(V_{EBP}/V_T) \quad [1] \\ V_{EBP} = V_T \ln(i_{Cp}/I_S) = 26m \ln(9.5m / 2.2 \times 10^{-15}) = 0.7564 \text{ V} \quad [1.5]$$

$$V_{BEN} = V_{BB} - V_{EBP} = 1.44 - 0.7564 = 0.6838 \text{ V} \quad [2] \\ i_{Cn} = I_S \exp(V_{BEN}/V_T) = 2.2 \times 10^{-15} \exp(0.6838/26m) = 575.9 \mu\text{A} \quad [1]$$

$$i_{Cn} = i_{Cp} + i_L \quad [0.5] \\ \text{Actual value of } i_{Cp} = i_{Cn} - i_L = 575.9 \mu\text{A} - (-9.5 \text{ mA}) = 10.0759 \text{ mA} \quad [1]$$

$$P_{Qn} = i_{Cn} V_{CEn} \quad [0.5] \\ V_{CEn} = +V_{CC} - v_O = +12 - (-9.5) = 21.5 \text{ V} \quad [1] \\ P_{Qn} = (575.9 \mu\text{A})(21.5 \text{ V}) = 12.38 \text{ mW} \quad [0.5]$$

**Question:**



**Figure 1**

For the **class AB** output stage in **Figure 1**, given that  $V_{CC} = 12 \text{ V}$  and  $V_{BB} = 1.42 \text{ V}$ .  $R_L = 1 \text{ k}\Omega$ . The reverse-bias saturation current for the transistors,  $I_S = 2.4 \times 10^{-15} \text{ A}$ . Assume  $\beta \gg 1$ .

For the output voltage  $v_O = -10.5 \text{ V}$ :

- (iii) Determine  $i_L$ ,  $i_{Cn}$ , and  $i_{Cp}$ . [8 marks]  
 (iv) Find the power dissipated in transistor  $Q_n$ . [2 marks]

**Answer:** (You may continue your answer in the next page)

$$v_O = -10.5 \text{ V} = i_L R_L \\ i_L = v_O / R_L = (-10.5 \text{ V}) / (1 \text{ k}\Omega) = -10.5 \text{ mA} \quad [1]$$

Therefore,  $Q_p$  is conducting and  $Q_n$  is OFF.

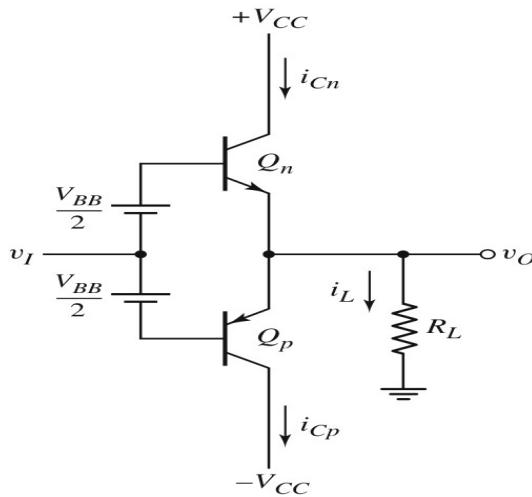
$$i_L \approx i_{Cp} = I_S \exp(V_{EBP}/V_T) \quad [1] \\ V_{EBP} = V_T \ln(i_{Cp}/I_S) = 26m \ln(10.5m / 2.4 \times 10^{-15}) = 0.7568 \text{ V} \quad [1.5]$$

$$V_{BEN} = V_{BB} - V_{EBP} = 1.42 - 0.7568 = 0.6632 \text{ V} \quad [2] \\ i_{Cn} = I_S \exp(V_{BEN}/V_T) = 2.4 \times 10^{-15} \exp(0.6632/26m) = 287.3 \mu\text{A} \quad [1]$$

$$i_{Cn} = i_{Cp} + i_L \quad [0.5] \\ \text{Actual value of } i_{Cp} = i_{Cn} - i_L = 287.3 \mu\text{A} - (-10.5 \text{ mA}) = 10.7873 \text{ mA} \quad [1]$$

$$P_{Qn} = i_{Cn} V_{CEn} \quad [0.5] \\ V_{CEn} = +V_{CC} - v_O = +12 - (-10.5) = 22.5 \text{ V} \quad [1] \\ P_{Qn} = (287.3 \mu\text{A})(22.5 \text{ V}) = 6.47 \text{ mW} \quad [0.5]$$

**Question:**



**Figure 1**

For the **class AB** output stage in **Figure 1**, given that  $V_{CC} = 14 \text{ V}$  and  $V_{BB} = 1.46 \text{ V}$ .  $R_L = 1 \text{ k}\Omega$ . The reverse-bias saturation current for the transistors,  $I_S = 2.4 \times 10^{-15} \text{ A}$ . Assume  $\beta \gg 1$ .

For the output voltage  $v_O = -10 \text{ V}$ :

- (v) Determine  $i_L$ ,  $i_{Cn}$ , and  $i_{Cp}$ . [8 marks]  
 (vi) Find the power dissipated in transistor  $Q_n$ . [2 marks]

**Answer:** (You may continue your answer in the next page)

$$v_O = -10 \text{ V} = i_L R_L \\ i_L = v_O / R_L = (-10 \text{ V}) / (1 \text{ k}\Omega) = -10 \text{ mA} \quad [1]$$

Therefore,  $Q_p$  is conducting and  $Q_n$  is OFF.

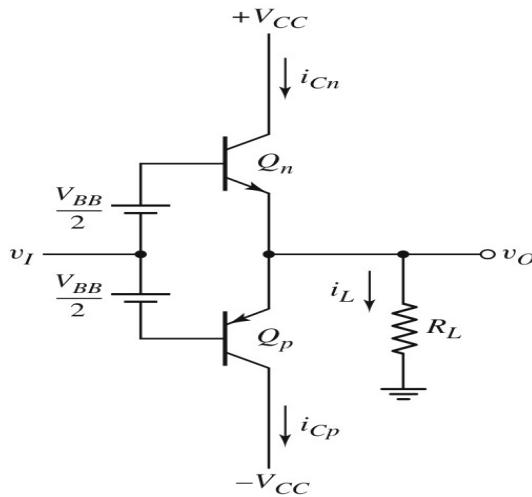
$$i_L \approx i_{Cp} = I_S \exp(V_{EBP}/V_T) \quad [1] \\ V_{EBP} = V_T \ln(i_{Cp}/I_S) = 26m \ln(10m / 2.4 \times 10^{-15}) = 0.7555 \text{ V} \quad [1.5]$$

$$V_{BEN} = V_{BB} - V_{EBP} = 1.46 - 0.7555 = 0.7045 \text{ V} \quad [2] \\ i_{Cn} = I_S \exp(V_{BEN}/V_T) = 2.4 \times 10^{-15} \exp(0.7045/26m) = 1405.2 \mu\text{A} \quad [1]$$

$$i_{Cn} = i_{Cp} + i_L \quad [0.5] \\ \text{Actual value of } i_{Cp} = i_{Cn} - i_L = 1405.2 \mu\text{A} - (-10m) = 11.4052 \text{ mA} \quad [1]$$

$$P_{Qn} = i_{Cn} V_{CEn} \quad [0.5] \\ V_{CEn} = +V_{CC} - v_O = +14 - (-10) = 24 \text{ V} \quad [1] \\ P_{Qn} = (1405.2 \mu\text{A})(24 \text{ V}) = 33.72 \text{ mW} \quad [0.5]$$

**Question:**



**Figure 1**

For the **class AB** output stage in **Figure 1**, given that  $V_{CC} = 12 \text{ V}$  and  $V_{BB} = 1.4 \text{ V}$ .  $R_L = 1 \text{ k}\Omega$ . The reverse-bias saturation current for the transistors,  $I_S = 2.4 \times 10^{-15} \text{ A}$ . Assume  $\beta \gg 1$ .

For the output voltage  $v_O = -8.5 \text{ V}$ :

- (vii) Determine  $i_L$ ,  $i_{Cn}$ , and  $i_{Cp}$ . [8 marks]  
 (viii) Find the power dissipated in transistor  $Q_n$ . [2 marks]

**Answer:** (You may continue your answer in the next page)

$$v_O = -8.5 \text{ V} = i_L R_L \\ i_L = v_O / R_L = (-8.5 \text{ V}) / (1 \text{ k}\Omega) = -8.5 \text{ mA} \quad [1]$$

Therefore,  $Q_p$  is conducting and  $Q_n$  is OFF.

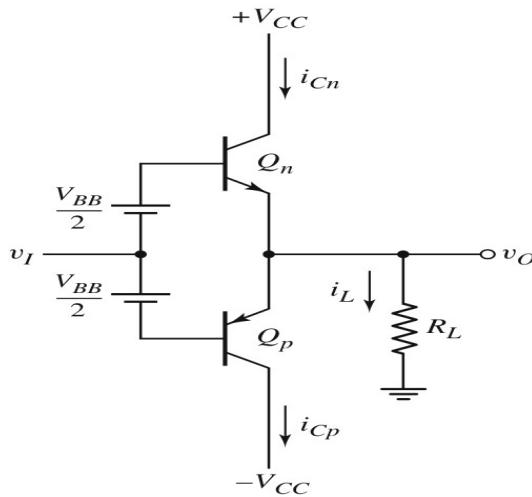
$$i_L \approx i_{Cp} = I_S \exp(V_{EBP}/V_T) \quad [1] \\ V_{EBP} = V_T \ln(i_{Cp}/I_S) = 26m \ln(8.5m / 2.4 \times 10^{-15}) = 0.7513 \text{ V} \quad [1.5]$$

$$V_{BEN} = V_{BB} - V_{EBP} = 1.4 - 0.7513 = 0.6487 \text{ V} \quad [2] \\ i_{Cn} = I_S \exp(V_{BEN}/V_T) = 2.4 \times 10^{-15} \exp(0.6487/26m) = 164.5 \mu\text{A} \quad [1]$$

$$i_{Cn} = i_{Cp} + i_L \quad [0.5] \\ \text{Actual value of } i_{Cp} = i_{Cn} - i_L = 164.5 \mu\text{A} - (-8.5 \text{ mA}) = 8.6645 \text{ mA} \quad [1]$$

$$P_{Qn} = i_{Cn} V_{CEn} \quad [0.5] \\ V_{CEn} = +V_{CC} - v_O = +12 - (-8.5) = 20.5 \text{ V} \quad [1] \\ P_{Qn} = (164.5 \mu\text{A})(20.5 \text{ V}) = 3.37 \text{ mW} \quad [0.5]$$

**Question:**



**Figure 1**

For the **class AB** output stage in **Figure 1**, given that  $V_{CC} = 12.5$  V and  $V_{BB} = 1.48$  V.  $R_L = 1$  k $\Omega$ . The reverse-bias saturation current for the transistors,  $I_S = 2.4 \times 10^{-15}$  A. Assume  $\beta \gg 1$ .

For the output voltage  $v_O = -9.5$  V:

- (ix) Determine  $i_L$ ,  $i_{Cn}$ , and  $i_{Cp}$ . [8 marks]  
 (x) Find the power dissipated in transistor  $Q_n$ . [2 marks]

**Answer:** (You may continue your answer in the next page)

$$v_O = -9.5 \text{ V} = i_L R_L \\ i_L = v_O / R_L = (-9.5 \text{ V}) / (1 \text{ k}\Omega) = -9.5 \text{ mA} \quad [1]$$

Therefore,  $Q_p$  is conducting and  $Q_n$  is OFF.

$$i_L \approx i_{Cp} = I_S \exp(V_{EBP}/V_T) \quad [1] \\ V_{EBP} = V_T \ln(i_{Cp}/I_S) = 26m \ln(9.5m / 2.4 \times 10^{-15}) = 0.7542 \text{ V} \quad [1.5]$$

$$V_{BEN} = V_{BB} - V_{EBP} = 1.48 - 0.7542 = 0.7258 \text{ V} \quad [2] \\ i_{Cn} = I_S \exp(V_{BEN}/V_T) = 2.4 \times 10^{-15} \exp(0.7258/26m) = 3192.1 \mu\text{A} \quad [1]$$

$$i_{Cn} = i_{Cp} + i_L \quad [0.5] \\ \text{Actual value of } i_{Cp} = i_{Cn} - i_L = 3192.1 \mu\text{A} - (-9.5 \text{ mA}) = 12.6921 \text{ mA} \quad [1]$$

$$P_{Qn} = i_{Cn} V_{CEn} \quad [0.5] \\ V_{CEn} = +V_{CC} - v_O = +12.5 - (-9.5) = 22 \text{ V} \quad [1] \\ P_{Qn} = (3192.1 \mu\text{A})(22 \text{ V}) = 70.23 \text{ mW} \quad [0.5]$$